

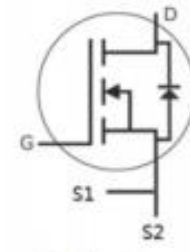
N-Channel MOSFET Transistor

FEATURES

- Reduced Switching Losses
- Ultra-fast Body Diode
- Higher System Efficiency

APPLICATIONS

- Switch Mode Power Supply (SMPS)
- Uninterruptible Power Supply (UPS)
- Suitable for Soft Switching Topologies

Absolute Maximum Ratings($T_c=25^\circ\text{C}$)

SYMBOL	PARAMETER	VALUE	UNIT
V_{DS}	Drain-Source Voltage	650	V
V_{GS}	Gate-Source Voltage-Continuous	± 20	V
I_D	Drain Current-Continuous@ $T_c=25^\circ\text{C}$	69	A
I_D	Drain Current-Continuous@ $T_c=100^\circ\text{C}$	44	A
I_{DM}	Drain Current-Single Pulse	304	A
P_D	Total Dissipation @ $T_c=25^\circ\text{C}$	305	W
T_J	Max. Operating Junction Temperature	150	$^\circ\text{C}$
T_{stg}	Storage Temperature	-55~150	$^\circ\text{C}$

THERMAL CHARACTERISTICS

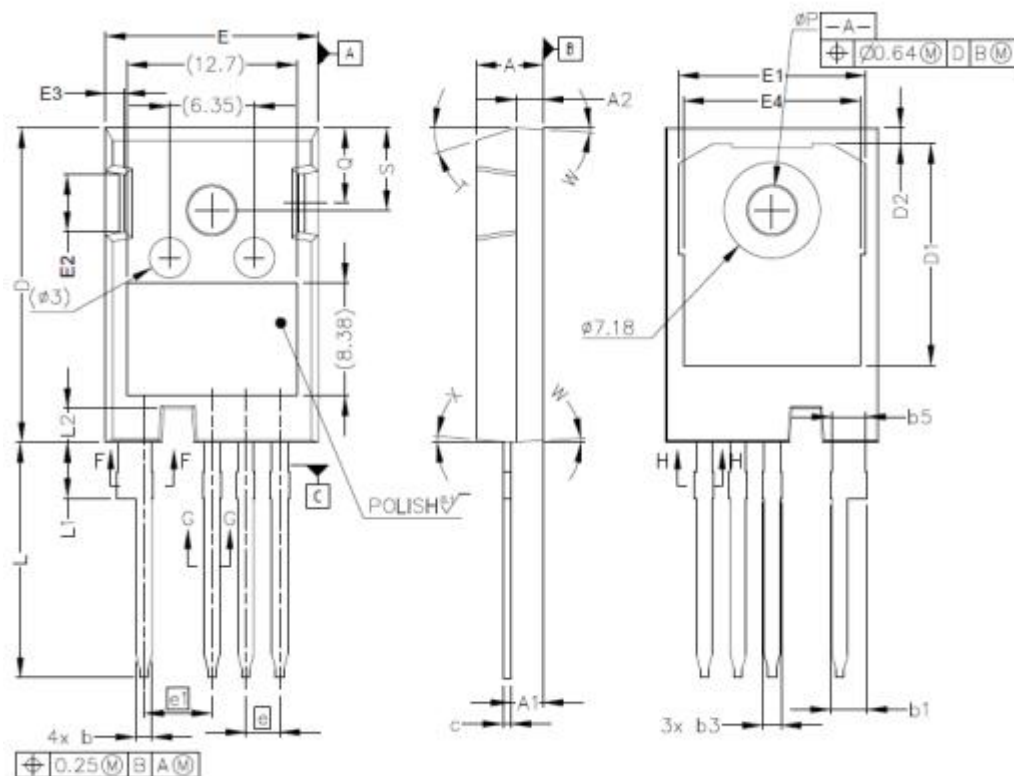
SYMBOL	PARAMETER	MAX	UNIT
$R_{th\ j-c}$	Thermal Resistance, Junction to Case	0.41	$^\circ\text{C}/\text{W}$

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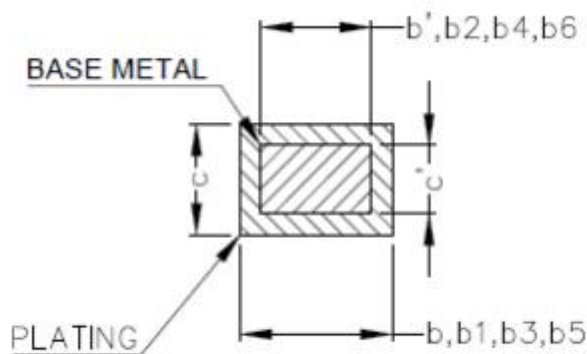
ELECTRICAL CHARACTERISTICS ($T_c=25^\circ\text{C}$)

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
$V_{(BR)DSS}$	Drain-Source Breakdown Voltage	$V_{GS} = 0, I_D = 1\text{mA}$	650	-	-	V
I_{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 650\text{V}, V_{GS} = 0$	-	-	1	μA
I_{GSS}	Gate-Body Leakage Current	$V_{GS} = \pm 20\text{V}, V_{DS} = 0$	-	-	± 100	nA
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = 1.8\text{mA}$	3.5	-	4.5	V
$R_{DS(on)}$	Drain-Source On-Resistance	$V_{GS} = 10\text{V}, I_D = 36\text{A}$	-	-	29	$\text{m}\Omega$
V_{SD}	Diode Forward Voltage	$I_{SD} = 36\text{A}, V_{GS} = 0\text{V}$	-	1.1	--	V

PACKAGE DIMENSIONS (UNIT: mm): TO-247-4



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SYMBOL	MILLIMETERS	
	MIN	MAX
A	4.83	5.21
A1	2.29	2.54
A2	1.91	2.16
b'	1.07	1.28
b	1.07	1.33
b1	2.39	2.94
b2	2.39	2.84
b3	1.07	1.60
b4	1.07	1.50
b5	2.39	2.69
b6	2.39	2.64
c'	0.55	0.65
c	0.55	0.68
D	23.30	23.60
D1	16.25	17.65
D2	0.95	1.25
E	15.75	16.13
E1	13.10	14.15
E2	3.68	5.10
E3	1.00	1.90
E4	12.38	13.43
e	2.54 BSC	
e1	5.08 BSC	
N	4	
L	17.31	17.82
L1	3.97	4.37
L2	2.35	2.65
øP	3.51	3.65
Q	5.49	6.00
S	6.04	6.30
T	17.5° REF.	
W	3.5° REF.	
X	4° REF.	

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